



SANYO Semiconductors

DATA SHEET

LA6358NMJM — Monolithic Linear IC High-Performance Dual Operational Amplifier

Overview

The LA6358NMJM is a high-performance dual operational amplifier that can operate from a single voltage power supply. It features a built-in phase correction circuit. It can also operate from a dual power supply with both positive and negative levels and features low power consumption. The LA6358NMJM can be used in a wide range of industrial applications as a transducer amplifier for all types of transducers, as a DC amplifier circuit, and for other purposes as well.

Functions

- High-performance dual operational amplifier

Specifications

Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V_{CC} max		32	V
Differential input voltage	V_{ID}		32	V
Maximum input voltage	V_{IN} max		-0.3 to +32	V
Allowable power dissipation	P_d max	$T_a \leq 25^\circ\text{C}$	300	mW
Operating temperature	T_{opr}		-40 to +85	$^\circ\text{C}$
Storage temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Recommended Operating Conditions at $T_a = -40$ to $+85^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Supply voltage	V_{CC}		3		24	V

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SANYO Semiconductor Co., Ltd.

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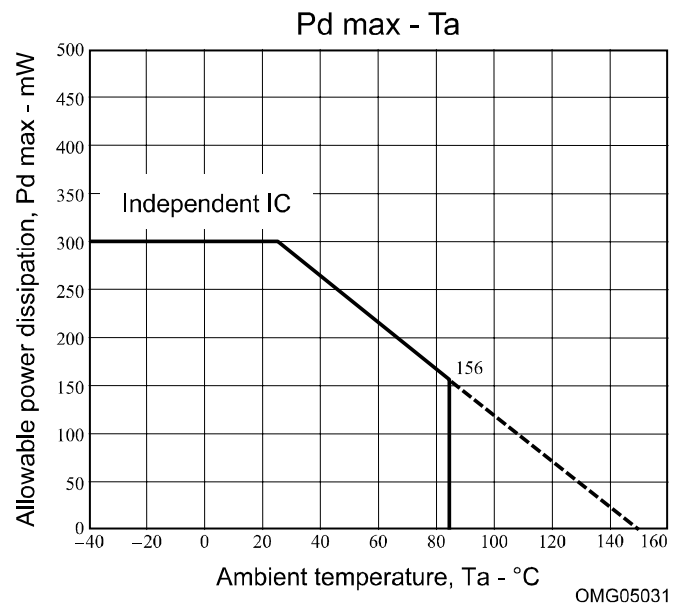
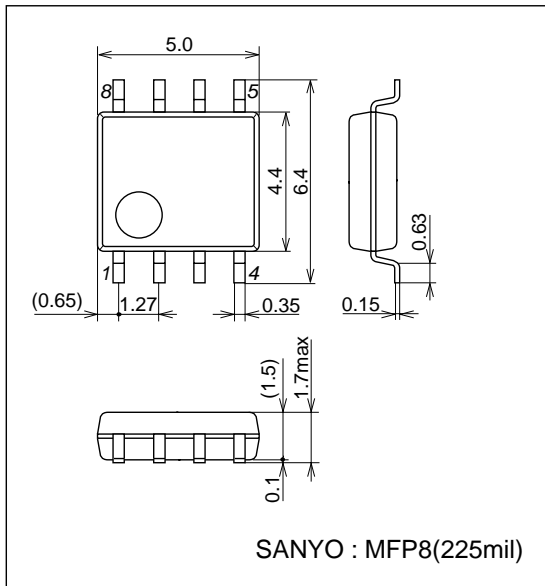
LA6358NMJM

Electrical Characteristics at $T_a = 25^\circ\text{C}$, $V_{CC} = 5\text{V}$

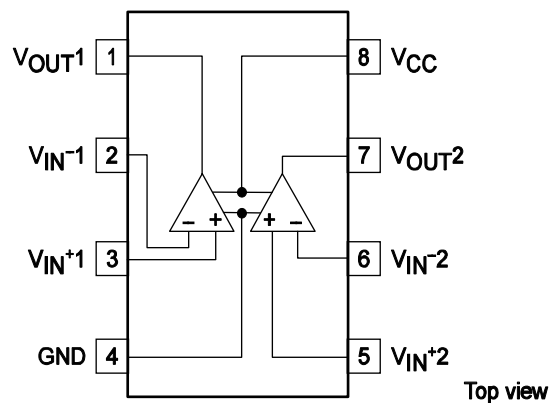
Parameter	Symbol	Conditions	Test circuit	Ratings			Unit
				min	typ	max	
Input offset voltage	V_{IO}		1		± 2	± 3	mV
Input offset current	I_{IO}	$I_{IN(+)} / I_{IN(-)}$	2		± 5	± 50	nA
Input bias current	I_B	$I_{IN(+)} / I_{IN(-)}$	3,4		45	250	nA
Common-mode input voltage range	V_{ICM}		5	0		$V_{CC}-1.5$	V
Common-mode rejection ratio	CMR	$V_{CC} = 30\text{V}$	5	65	80		dB
Large-amplitude voltage gain	VG	$V_{CC} = 15\text{V}$, $R_L \geq 2\text{k}\Omega$	6	25	100		V/mV
Output voltage range	V_{OUT}			0		$V_{CC}-1.5$	V
Supply voltage rejection ratio	SVR		11	65	100		dB
Channel separation	CS	$f = 1\text{ k to } 20\text{ kHz}$	7		120		dB
Current drain	I_{CC}		8		0.5	1.2	mA
Output current (source)	$I_{O \text{ source}}$	$V_{IN+} = 1\text{V}$, $V_{IN-} = 0\text{V}$	9	20	40		mA
Output current (sink)	$I_{O \text{ sink}}$	$V_{IN+} = 0\text{V}$, $V_{IN-} = 1\text{V}$	10	10	20		mA

Package Dimensions

unit : mm
3032D

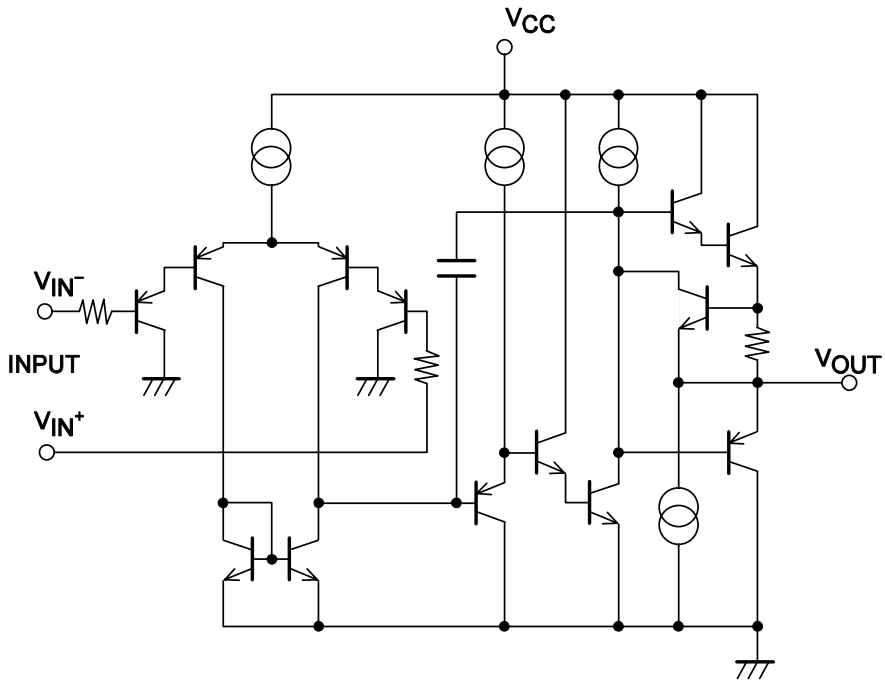


Pin Assignment



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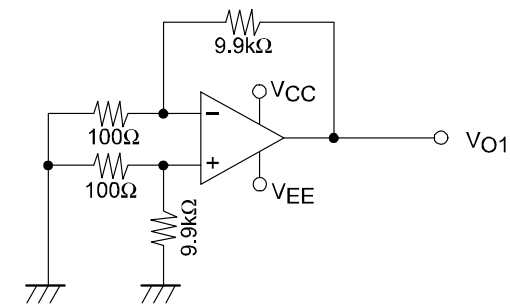
Equivalent Circuit



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Test Circuits

1. Input offset voltage V_{IO}

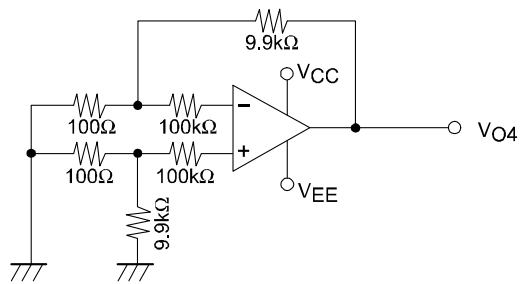


$$V_{CC} / V_{EE} = \pm 15V$$

$$V_{IO} = V_{O1} / 100$$

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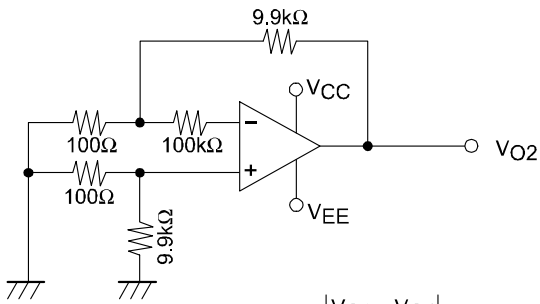
2. Input offset current I_{IO}



$$I_{IO} = \frac{|V_{O4} - V_{O1}|}{100K\Omega \times 100}$$

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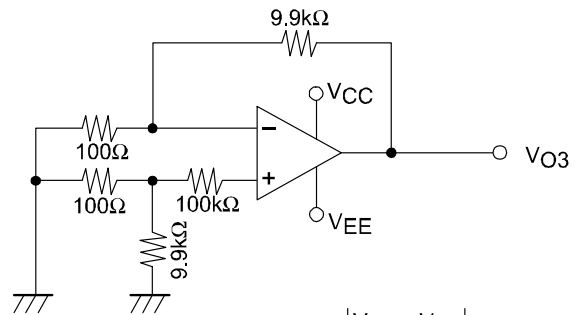
3. Input bias current $I_B (-)$



$$I_B(-) = \frac{|V_{O2} - V_{O1}|}{100K\Omega \times 100}$$

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4. Input bias current $I_B (+)$

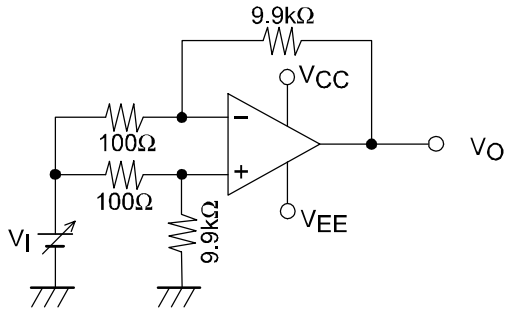


$$I_B(+) = \frac{|V_{O3} - V_{O1}|}{100K\Omega \times 100}$$

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LA6358NMJM

5. Common-mode rejection ratio CMR Common-mode input voltage range VICN

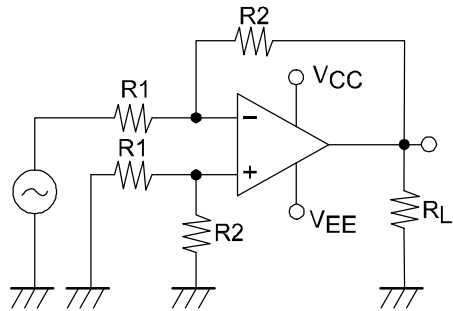


$$\text{CMR } V_I = \pm 7.5\text{V}$$

$$\text{CMR} = 20 \log \frac{15 \times 100}{|\Delta V_O|}$$

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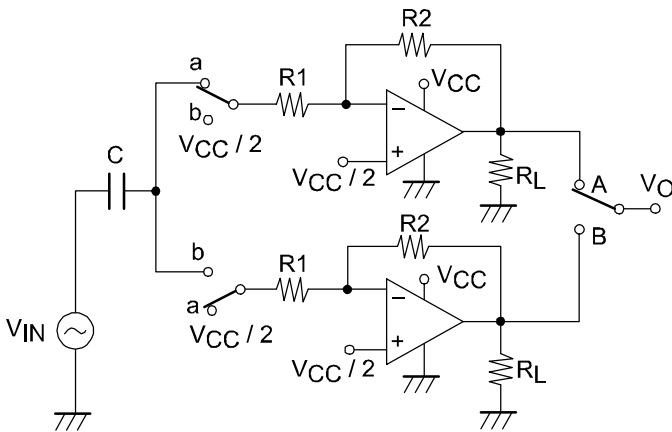
6. Voltage gain V_G



$$V_G = \frac{R_2}{R_1}$$

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7. Channel separation CH sep



When the switch is in the "a" position

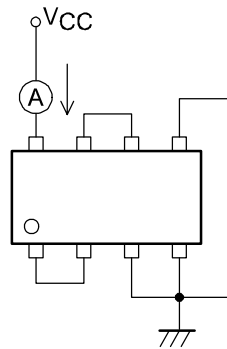
$$\text{CS}(A \rightarrow B) = 20 \log \frac{R_2 V_{OA}}{R_1 V_{OB}}$$

When the switch is in the "b" position

$$\text{CS}(B \rightarrow A) = 20 \log \frac{R_2 V_{OB}}{R_1 V_{OA}}$$

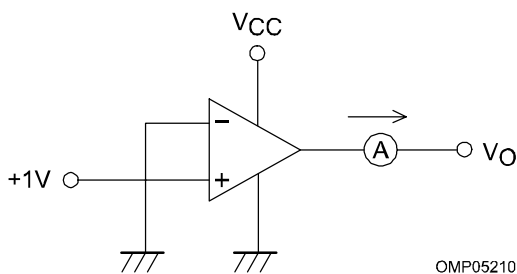
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8. Current drain I_{CC}



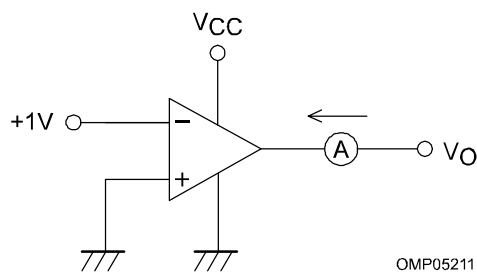
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9. Output current I_O source



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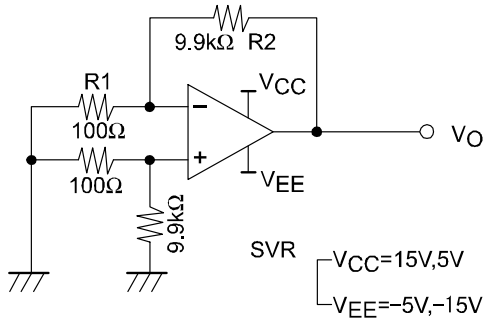
10. Output current I_O sink



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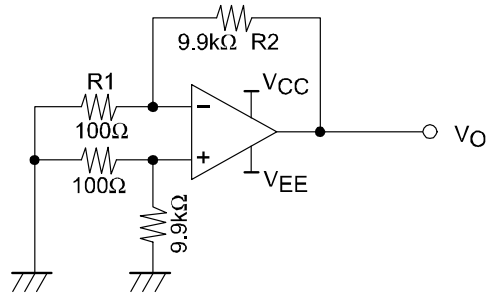
LA6358NMJM

11. Supply voltage rejection ratio SVR (+)



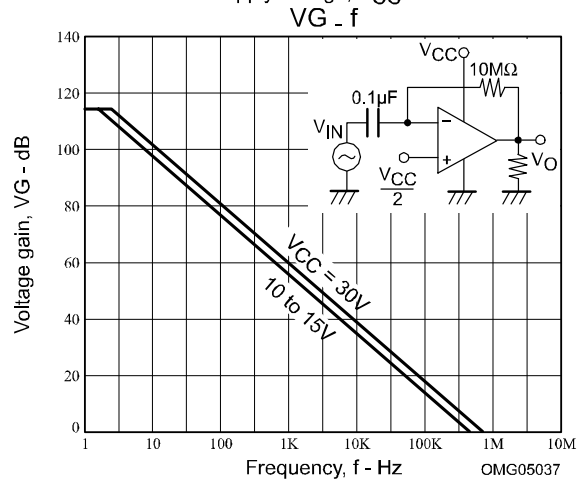
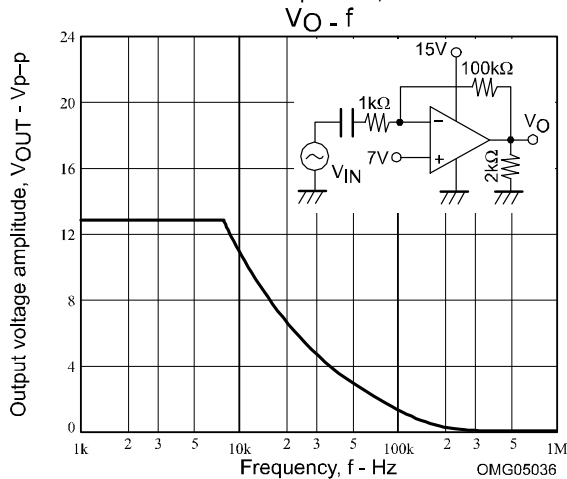
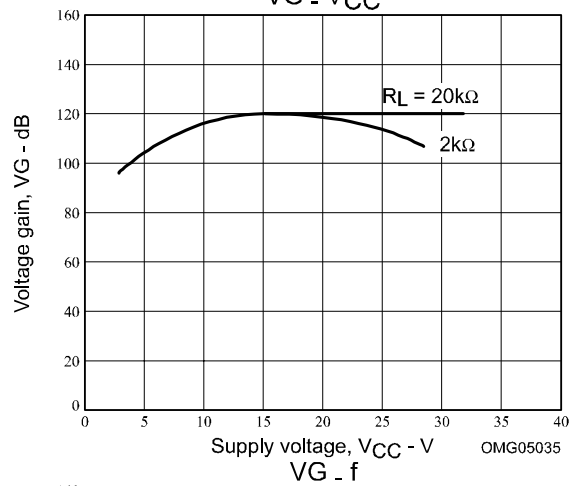
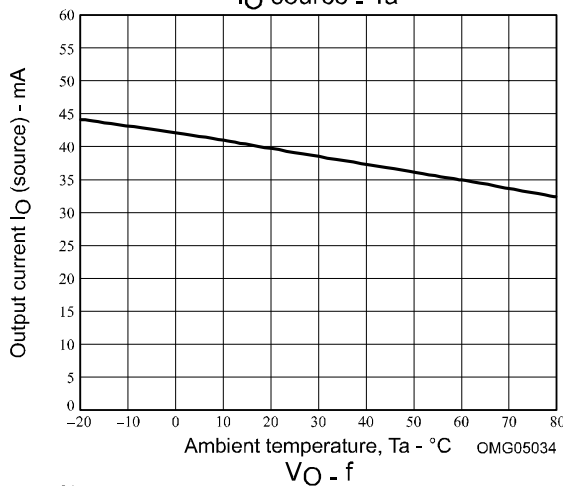
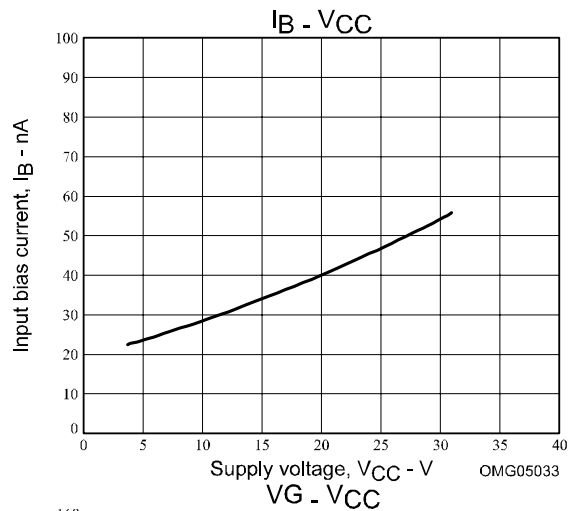
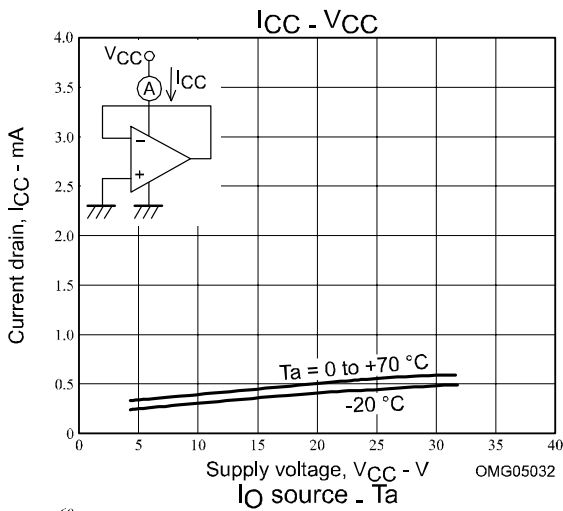
$$SVR(+)=20\log \left| \frac{\Delta V_{CC} \times 100}{\Delta V_O} \right|$$

12. Supply voltage rejection ratio SVR (-)



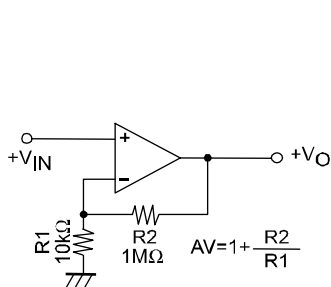
$$SVR(-)=20\log \left| \frac{\Delta V_{EE} \times 100}{\Delta V_O} \right|$$

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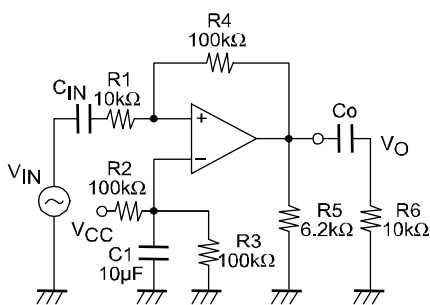
Application Circuit Examples

Noninverting DC amplifier



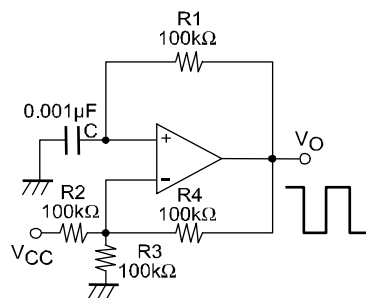
$$AV = 1 + \frac{R2}{R1}$$

Inverting AC amplifier



$$AV = -\frac{R4}{R1}$$

Square wave generator



OMB05077

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